

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant :	Garbuzov et al.	Art Unit :	2828
Serial No. :	10/778,019	Examiner :	Dung T. Nguyen
Filed :	February 13, 2004	Conf. No. :	4607
Title :	HIGH POWER SEMICONDUCTOR LASER DIODE		

MAIL STOP AMENDMENT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Applicants request consideration of the references listed on the attached PTO-1449 form. Under 37 C.F.R. § 1.98 (a)(2)(ii), only copies of foreign patent documents and/or non-patent literature are enclosed. Copies of any listed U.S. patents or U.S. patent application publications can be provided upon request.

This statement is being filed after a first Office action on the merits, but before receipt of a final Office action or a Notice of Allowance. The fee for \$180 in payment of the late submission fee of §1.17(p) is being filed concurrently with the Electronic Filing System (EFS). Please apply all charges or credits to Deposit Account No. 06-1050, referencing Attorney Docket No. 14564-006002.

Respectfully submitted,

Date: August 21, 2007

/Diana DiBerardino/

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Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 14564-006002	Application No. 10/778,019
	Applicant Garbuzov et al.		
	Filing Date February 13, 2004	Group Art Unit 2828	

U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AL	JP 04-234188	08/21/92	Japan			Abst	
	AM	JP 07-045909	02/14/95	Japan			Abst	
	AN	JP 07-335979	12/22/95	Japan			Abst	
	AO	JP 08-064906	03/08/96	Japan			Abst	
	AP	JP 08-195529	07/30/96	Japan			Abst	

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	AQ	Copy of Office Action from corresponding Japanese Application No. PH09-363805, mailed February 20, 2007, English translation included (15 total pages).
	AR	Ito, R. and Nakamura, M., <i>Foundation and Application of Semiconductor Laser</i> , BAIFUKAN CO., LTD., 1 st Edition, 5 th printing, pp. 50-53 and 82-84, March 30, 1995 (Japan).
	AS	
	AT	

Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	